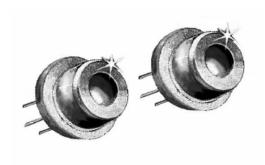
LASER DIODE RPMC-915-0300-S50-xx



RPMC-915-0300-S50-xx is 915nm AlGaAs quantum well fabricated by MOCVD semiconductor laser. Low threshold current and high slope efficiency contribute to low operating current enhancing reliability.

RPMC-915-0300-S50-xx is a CW single mode injection semiconductor laser available in 9mm TO-can or chip on sub mount package. The laser diode is suitable for application in various opto-electronic systems.

Optical and electrical characteristics (T = 25°C, P = 300mW):

Operating Parameters	Symbol	Min	Тур	Max	Unit
Optical output power	Pout	-	300	-	mW
Wavelength	λ	910	915	920	nm
Spectrum	FWHM Δλ	-	0.5	2.0	nm
Threshold current	Ith	-	30	50	mA
Forward current	lf	-	370	420	mA
Forward voltage	Vf	-	1.9	2.2	V
Slope efficiency	ΔΡ/ΔΙ	8.0	0.9	-	W/A
Vertical far field	Θ	-	28	30	0
Parallel far field	Θ⊥	-	8	10	0

Specifications are subject to change without notice.

TE Polarized

Additional information:

- wavelength drift under temperature change <0,3nm/°C;
- - LD reverse voltage 2V;
- - PD reverse voltage 30V;
- - operating temperature -20°C +50°C;
- - storage temperature -40°C +80°C
- - lifetime >100000 hours
- - lead soldering temperature 250°C for 5sec

Available Packages:

C2 chip on 2.1mm sub mount

M9 9mm TO-can with or without PD



203 Joseph Street O'Fallon, MO 63366 www.rpmclasers.com Tel: (636) 272-7227 Fax: (636) 272-3909

email: diodes@rpmclasers.com